

**PATENT APPLICATION COVER SHEET**

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**25700**

PATENT TRADEMARK OFFICE

22388 U.S. PTO  
10/678445  
100303

Sir/Madam:

Transmitted herewith is the patent application of:

Inventor(s): George Jonathan Kluth, Joong S. Jeon, Qi Xiang and Huicai Zhong

For: "Method for Forming Polysilicon Gate on High-K Dielectric and Related Structure"

☐ This application is a ☐ Continuation ☐ Divisional ☐ Continuation-in-part (CIP) of prior application  
No.: \_\_\_\_\_.

Enclosed are:

- ☒ Three (3) Sheets of drawings
- ☒ Request for Non-Publication (Form PTO/SB/35 (11-00))
- ☒ An assignment of the invention to Advanced Micro Devices, Inc.
- ☒ The enclosed payment includes \$40.00 for the recording of the assignment
- ☐ Applicant(s) claim(s) small entity status
- ☐ Information Disclosure Statement
- ☐ Preliminary Amendment
- ☒ Declaration and Power of Attorney
- ☒ The filing fee has been calculated as shown below:

	(Col. 1)	(Col. 2)
FOR:	No. Filed	No. Extra
BASIC FEE		
TOTAL CLAIMS	20 -20 =	0
INDEPENDENT CLAIMS	3 -3 =	0
MULTIPLE DEPENDENT CLAIMS PRESENTED		

If the difference in Col. 1 is less than zero,  
enter "0" in Col. 2

**SMALL ENTITY**

RATE	FEE
	\$385.00
x 9 =	\$
x 43 =	\$
+145 =	\$
<b>TOTAL</b>	<b>\$</b>

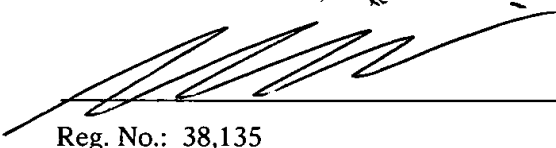
**OTHER THAN A  
SMALL ENTITY**

RATE	FEE
	\$770.00
x 18 =	\$0.00
x 86 =	\$0.00
+290 =	\$
<b>TOTAL</b>	<b>\$770.00</b>

- ☒ Enclosed is a payment in the amount of \$810.00 by credit card (Form PTO-2038 attached).
- ☐ Please charge Deposit Account No. 50-0731 in the amount of \$ \_\_\_\_\_.
- ☒ The Commissioner is hereby authorized to charge payment of any additional fees associated with this communication, or credit any overpayment to Deposit Account No. 50-0731. A duplicate copy of this sheet is enclosed.

MICHAEL FARJAMI, ESQ.

Date: 10/3/03

  
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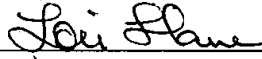
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<b>NONPUBLICATION REQUEST UNDER 35 U.S.C. 122(b)(2)(B)(i)</b>	First Named Inventor	Kluth, et al.
	Title	Method for Forming Polysilicon Gate on High-K Dielectric and Related Structure
	Atty Docket Number	0180146

I hereby certify that the invention disclosed in the attached application **has not and will not be** the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing.

I hereby request that the attached application not be published under 35 U.S.C. 122(b).

10/3/03  
Date

  
Signature

Michael Farjami, Esq.  
Typed or printed name

This request must be signed in compliance with 37 CFR 1.33(b) and submitted with the application **upon filing**.

Applicant may rescind this nonpublication request at any time. If applicant rescinds a request that an application not be published under 35 U.S.C. 122(b), the application will be scheduled for publication at eighteen months from the earliest claimed filing date for which a benefit is claimed.

If applicant subsequently files an application directed to the invention disclosed in the attached application in another country, or under a multilateral international agreement, that requires publication of applications eighteen months after filing, the applicant **must** notify the United States Patent and Trademark Office of such filing within forty-five (45) days after the date of the filing of such foreign or international application. **Failure to do so will result in abandonment of this application (35 U.S.C. 122(b)(2)(B)(iii)).**